



2N7002

#### N-CHANNEL ENHANCEMENT MODE FIELD EFFECT TRANSISTOR

### **Features**

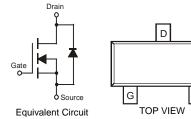
- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Lead, Halogen and Antimony Free, RoHS Compliant (Note 2)
- "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### **Mechanical Data**

- Case: SOT-23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020D
- Terminals: Solderable per MIL-STD-202, Method 208
- Lead Free Plating (Matte Tin Finish annealed over Alloy 42 leadframe).
- Terminal Connections: See Diagram
- Marking Information: See Page 3
- Ordering Information: See Page 3
- Weight: 0.008 grams (approximate)



SOT-23



### **Maximum Ratings** @T<sub>A</sub> = 25°C unless otherwise specified

Characte	Symbol	Value	Units	
Drain-Source Voltage		$V_{DSS}$	60	V
Drain-Gate Voltage R <sub>GS</sub> ≤ 1.0MΩ		$V_{DGR}$	60	V
Gate-Source Voltage	Continuous Pulsed	V <sub>GSS</sub>	±20 ±40	V
Drain Current (Note 1)	Continuous Continuous @ 100°C Pulsed	I <sub>D</sub>	115 73 800	mA

### Thermal Characteristics @TA = 25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Total Power Dissipation (Note 1)	D-	300	mW
Derating above T <sub>A</sub> = 25°C	P <sub>D</sub>	2.4	mW/°C
Thermal Resistance, Junction to Ambient	$R_{ hetaJA}$	417	°C/W
Operating and Storage Temperature Range	T <sub>J</sub> , T <sub>STG</sub>	-55 to +150	°C

Notes:

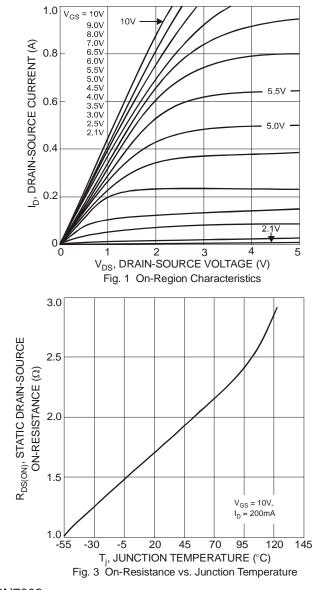
- 1. Device mounted on FR-4 PCB 1.0 x 0.75 x 0.062 inch pad layout as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com/datasheets/ap02001.pdf.
- No purposefully added lead. Halogen and Antimony Free.
  Product manufactured with Date Code V9 (week 33, 2008) and newer are built with Green Molding Compound. Product manufactured prior to Date Code V9 are built with Non-Green Molding Compound and may contain Halogens or Sb<sub>2</sub>O<sub>3</sub> Fire Retardants.



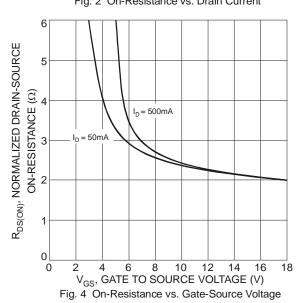
# **Electrical Characteristics** @T<sub>A</sub> = 25°C unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 4)		,		•	•		
Drain-Source Breakdown Voltage		BV <sub>DSS</sub>	60	70	_	V	$V_{GS} = 0V, I_D = 10\mu A$
Zero Gate Voltage Drain Current	@ T <sub>C</sub> = 25°C	I <sub>DSS</sub>			1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
	@ T <sub>C</sub> = 125°C	1033			500	μ, ,	VDS = 00 V, VGS = 0 V
Gate-Body Leakage		I <sub>GSS</sub>	_	_	±10	nA	$V_{GS} = \pm 20V$ , $V_{DS} = 0V$
ON CHARACTERISTICS (Note 4)				•	•	•	
Gate Threshold Voltage		V <sub>GS(th)</sub>	1.0	_	2.5	V	$V_{DS} = V_{GS}$ , $I_D = 250 \mu A$
Static Drain-Source On-Resistance	@ $T_i = 25^{\circ}C$	D	_	3.2 4.4	7.5 13.5	Ω	$V_{GS} = 5.0V, I_D = 0.05A$
	@ $T_j = 125$ °C	R <sub>DS</sub> (ON)					$V_{GS} = 10V, I_D = 0.5A$
On-State Drain Current		I <sub>D(ON)</sub>	0.5	1.0	_	Α	$V_{GS} = 10V, V_{DS} = 7.5V$
Forward Transconductance		g <sub>FS</sub>	80	_	_	mS	$V_{DS} = 10V, I_D = 0.2A$
DYNAMIC CHARACTERISTICS							
Input Capacitance		C <sub>iss</sub>	_	22	50	pF	\/ OF\/ \/ O\/
Output Capacitance		Coss	_	11	25	pF	$V_{DS} = 25V, V_{GS} = 0V$ - f = 1.0MHz
Reverse Transfer Capacitance		$C_{rss}$	_	2.0	5.0	pF	1 = 1.01/1112
SWITCHING CHARACTERISTICS		,			•	•	•
Turn-On Delay Time		t <sub>D(ON)</sub>	_	7.0	20	ns	$V_{DD} = 30V, I_D = 0.2A,$
Turn-Off Delay Time		t <sub>D(OFF)</sub>	_	11	20	ns	$R_L = 150\Omega, V_{GEN} = 10V,$
		*D(OFF)			_0	110	$R_{GEN} = 25\Omega$

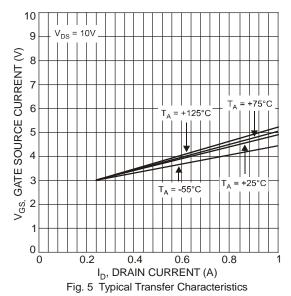
4. Short duration pulse test used to minimize self-heating effect.



7 T<sub>j</sub> = 25°C R<sub>DS(ON)</sub>, NORMALIZED DRAIN-SOURCE ON-RESISTANCE (Ω) V<sub>GS</sub> = 5.0V V<sub>GS</sub> = 10V 0 0.2 0.4 0.6 8.0 0 1.0 I<sub>D</sub>, DRAIN CURRENT (A) Fig. 2 On-Resistance vs. Drain Current







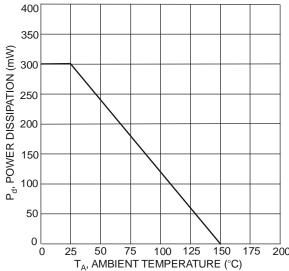


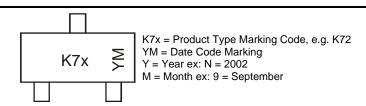
Fig. 6 Max Power Dissipation vs. Ambient Temperature

## **Ordering Information** (Note 5)

Part Number	Case	Packaging
2N7002-7-F	SOT-23	3000/Tape & Reel

Notes: 5. For packaging details, go to our website at http://www.diodes.com/datasheets/ap02007.pdf.

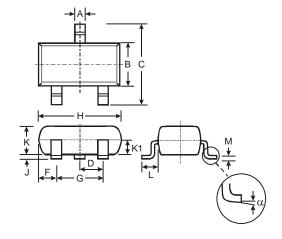
## **Marking Information**



Date Code Key

Year	1998	1999	2000	2001	2002	2003	2004	2005	2006	2007	2008	2009	2010	2011	2012
Code	J	K	L	M	N	Р	R	S	Т	U	V	W	X	Υ	Z
Month	Jan	Fe	b I	Mar	Apr	May	Ju	n	Jul	Aug	Sep	Oc	t	Nov	Dec
Code	1	2		3	4	5	6		7	8	9	0		N	D

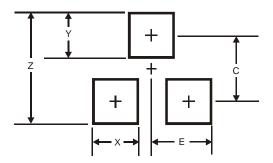
# **Package Outline Dimensions**



SOT-23						
Dim	Min	Max	Тур			
Α	0.37	0.51	0.40			
В	1.20	1.40	1.30			
С	2.30	2.50	2.40			
D	0.89	1.03	0.915			
F	0.45	0.60	0.535			
G	1.78	2.05	1.83			
Н	2.80	3.00	2.90			
J	0.013	0.10	0.05			
K	0.903	1.10	1.00			
K1	-	-	0.400			
L	0.45	0.61	0.55			
M	0.085	0.18	0.11			
α	0°	8°	-			
All Dimensions in mm						



### **Suggested Pad Layout**



Dimensions	Value (in mm)				
Z	2.9				
Х	0.8				
Υ	0.9				
С	2.0				
E	1.35				

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